



SANGDEST
MICROELECTRONICS

ST8200
STB8200
STF8200
STD8200

Technical Data
Data Sheet N1428, Rev. -

Green Products

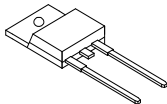
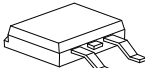
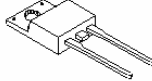
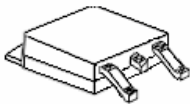
ST8200/STB8200/STF8200/STD8200 SCHOTTKY RECTIFIER

Applications:

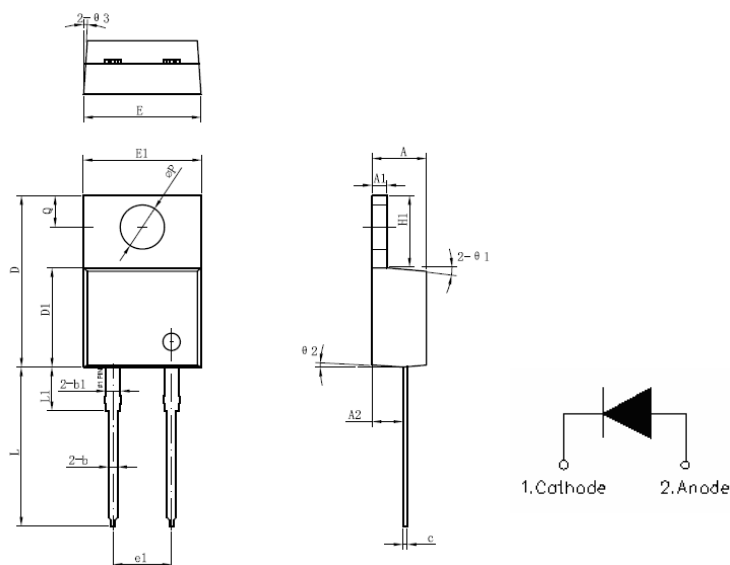
- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Features:

- 150 °C T_J operation
- Center tap configuration
- Ultralow forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Case styles			
ST8200  TO-220AC	STB8200  D²PAK	STF8200  ITO-220AC	STD8200  DPAK

Mechanical Dimensions: In Inches / mm



TO-220AC

Symbol	Dimensions in millimeters		
	Min.	Typical	Max.
A	4.55	4.70	4.85
A1	1.17	1.27	1.37
A2	2.59	2.69	2.89
b	0.71	0.81	0.96
b1		1.27	
c	0.36	0.38	0.61
D	14.64	14.94	15.24
D1	8.55	8.07	8.85
E	10.01	10.16	10.31
E1	9.98	10.18	10.38
e1		5.08	
H1	6.04	6.24	6.44
L	13.00	13.86	14.08
L1		3.80	
ΦP	3.74	3.84	4.04
Q	2.54	2.74	2.94
Θ1		5°	
Θ2		4°	
Θ3		4°	

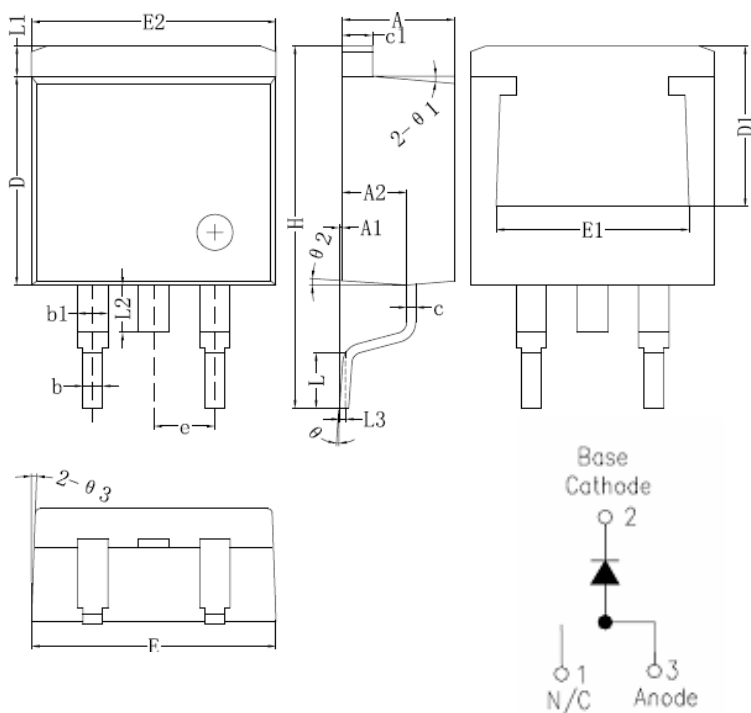


SANGDEST
MICROELECTRONICS

ST8200
STB8200
STF8200
STD8200

Technical Data
Data Sheet N1428, Rev. -

Green Products



Symbol	Dimensions in millimeters		
	Min.	Typical	Max.
A	4.55	4.70	4.85
A1	0	0.10	0.25
A2	2.59	2.69	2.89
b	0.71	0.81	0.96
b1		1.27	
c	0.36	0.38	0.61
c1	1.17	1.27	1.37
D	8.55	8.70	8.85
D1	6.40		
E	10.01	10.16	10.31
E1	7.6		
E2	9.98	10.08	10.18
e		2.54	
H	14.6	15.1	15.6
L	2.00	2.30	2.70
L1	1.17	1.27	1.40
L2			2.20
L3		0.25BSC	
e	0	-	8°
e1		5°	
e2		4°	
e3		4°	

D²PAK

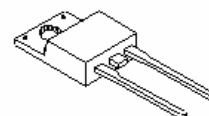
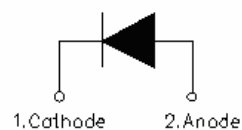
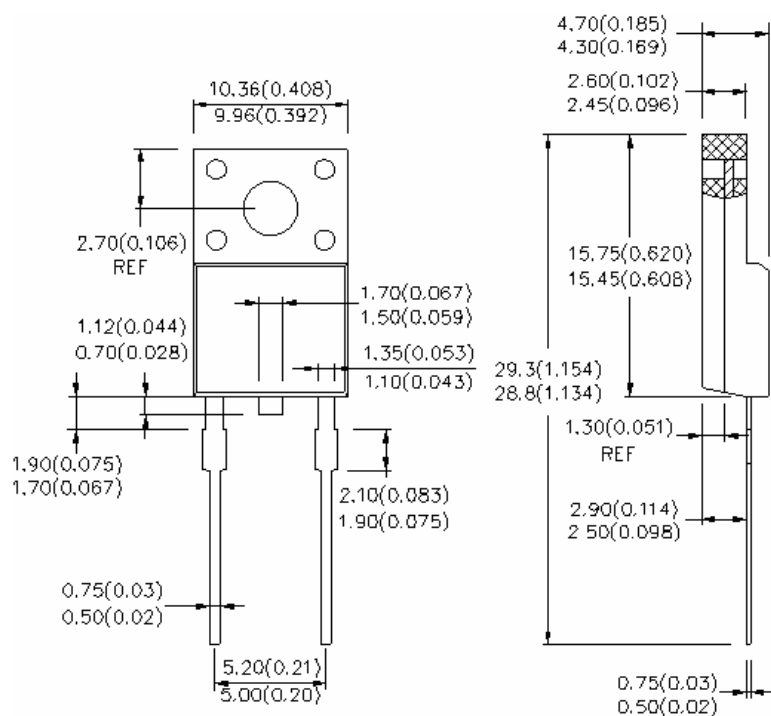


SANGDEST
MICROELECTRONICS

ST8200
STB8200
STF8200
STD8200

Technical Data
Data Sheet N1428, Rev. -

Green Products



ITO-220AC

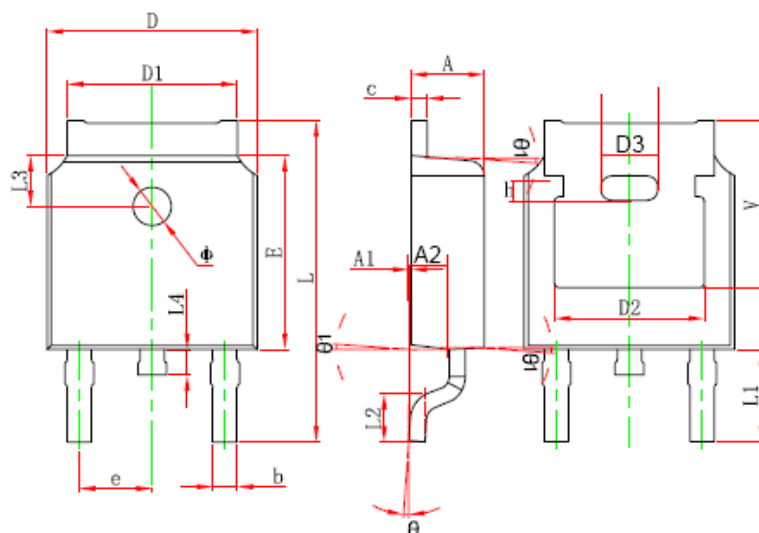


SANGDEST
MICROELECTRONICS

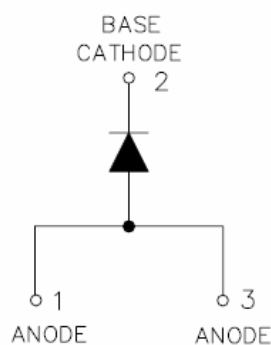
ST8200
STB8200
STF8200
STD8200

Technical Data
Data Sheet N1428, Rev. -

Green Products



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	2.200	2.380	0.087	0.094
A1	0.000	0.100	0.000	0.004
b	0.710	0.810	0.028	0.032
c	0.460	0.560	0.018	0.022
D	6.500	6.700	0.256	0.264
D1	5.130	5.460	0.202	0.215
D2	4.830 REF.		0.190 REF.	
E	6.000	6.200	0.236	0.244
e	2.186	2.386	0.086	0.094
L	9.800	10.400	0.386	0.409
L1	2.900 REF.		0.114 REF.	
L2	1.400	1.700	0.055	0.067
L3	1.600 REF.		0.063 REF.	
L4	0.600	1.000	0.024	0.039
Φ	1.100	1.300	0.043	0.051
θ	0°	8°	0°	8°
A2	0.910	1.110	0.036	0.044
V	5.350 REF.		0.211 REF.	
D3	1.778 REF.		0.070 REF.	
h	0.762 REF.		0.030 REF.	
θ1	7°		7°	



DPAK



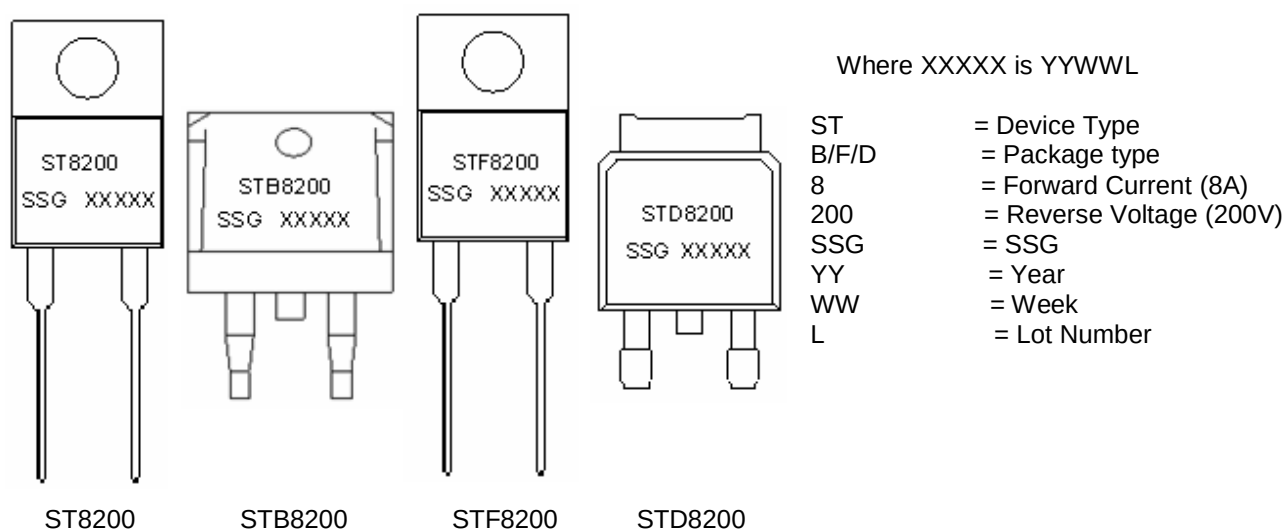
SANGDEST
MICROELECTRONICS

ST8200
STB8200
STF8200
STD8200

Technical Data
Data Sheet N1428, Rev. -

Green Products

Marking Diagram:



Cautions: Molding resin
Epoxy resin UL: 94V-0

Ordering Information:

Device	Package	Shipping
ST8200	TO-220AC(Pb-Free)	50pcs / tube
STB8200	D ² PAK(Pb-Free)	800pcs / reel
STF8200	ITO-220AC(Pb-Free)	50pcs / tube
STD8200	DPAK(Pb-Free)	2500pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	200	V
Average Forward Current	$I_{F(AV)}$	50% duty cycle @ $T_C = 100^\circ\text{C}$, rectangular wave form	8	A
Peak One Cycle Non-Repetitive Surge Current (per leg)	I_{FSM}	8.3 ms, half Sine pulse	130	A

• Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 ☎ (86) 25-87123907 •
• FAX (86) 25-87123900 • World Wide Web Site - <http://www.sangdest.com.cn> • E-Mail Address - sales@sangdest.com.cn •



Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 8A, Pulse, T _J = 25 °C	1.60	V
	V _{F2}	@ 8A, Pulse, T _J = 125 °C	0.73	V
Reverse Current*	I _{R1}	@V _R = rated V _R T _J = 25 °C	0.24	mA
	I _{R2}	@V _R = rated V _R T _J = 125 °C	16	mA
Junction Capacitance (per leg)	C _T	@V _R = 5V, T _C = 25 °C f _{SiG} = 1MHz	450	pF
Voltage Rate of Change	dv/dt	-	10,000	V/μs

* Pulse Width < 300μs, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	ST8200	STB8200	STD8200	STF8200	Units
Junction Temperature	T _J	-55 to +150				°C
Storage Temperature	T _{stg}	-55 to +150				°C
Maximum Thermal Resistance Junction to Case(per leg)*	R _{θJC}	2.8	2.8	2.0	5.5	°C/W
Approximate Weight	wt	1.8	1.85	0.39	1.8	g
Case Style	TO-220AC/ D ² PAK/ DPAK/ ITO-220AC					



SANGDEST
MICROELECTRONICS

ST8200
STB8200
STF8200
STD8200

Technical Data
Data Sheet N1428, Rev. -

Green Products

DISCLAIMER:

1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the SMC - Sangdest Microelectronics (Nanjing) Co., Ltd sales department for the latest version of the datasheet(s).

2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.

3- In no event shall SMC - Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). SMC - Sangdest Microelectronics (Nanjing) Co., Ltd assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.

4- In no event shall SMC - Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.

5- No license is granted by the datasheet(s) under any patents or other rights of any third party or SMC - Sangdest Microelectronics (Nanjing) Co., Ltd.

6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of SMC - Sangdest Microelectronics (Nanjing) Co., Ltd.

7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations..